Solutions to  $\it The \ Art \ of \ Electronics \ 3rd \ Edition$ 

December 26, 2023

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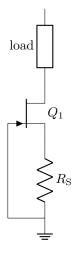
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## Solutions for Chapter 3

## Exercise 3.1

Figure 1.1: JFET current source



From Figure 3.21 of the book, one can see that a drain current equal to  $1\,\mathrm{mA}$  corresponds to a gate-source voltage of  $-0.6\,\mathrm{V}$ . Therefore:

$$R_{\rm S} = \frac{0.6\,\mathrm{V}}{1\,\mathrm{mA}} = 600\,\Omega$$

Exercise 3.3 TODO: write solution

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